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June 2003

FDS6670A

FAIRCHILD SEMICONDUCTOR

Single N-Channel, Logic Level, PowerTrench^o MOSFET

General Description

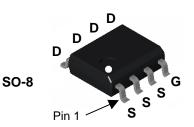
This N-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

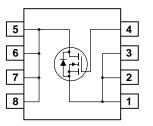
These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.

Features

- 13 A, 30 V. $\begin{array}{l} R_{\text{DS}(\text{ON})} = 8 \; m\Omega \; @ \; V_{\text{GS}} = 10 \; \text{V} \\ R_{\text{DS}(\text{ON})} = 10 \; m\Omega \; @ \; V_{\text{GS}} = 4.5 \; \text{V} \end{array}$
- Fast switching speed
- Low gate charge
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability

12mm





Absolute Maximum Ratings T_A=25°C unless otherwise noted

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Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Source Voltage			30	V
V _{GSS}	Gate-Sourc	e Voltage		±20	V
I _D	Drain Current – Continuous (Note 1a)		13	А	
		– Pulsed		50	
PD	Power Diss	pation for Single Operation	(Note 1a)	2.5	W
			(Note 1b)	1.0	
T _J , T _{STG}	Operating a	rating and Storage Junction Temperature Range		-55 to +150	°C
Therma	I Charac	teristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)		50	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1b)				
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 1)			25	
Packag	e Markin	g and Ordering Inf	formation		
Device	Marking	Device	Reel Size	Tape width	Quantity

13"

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FDS6670A

2500 units

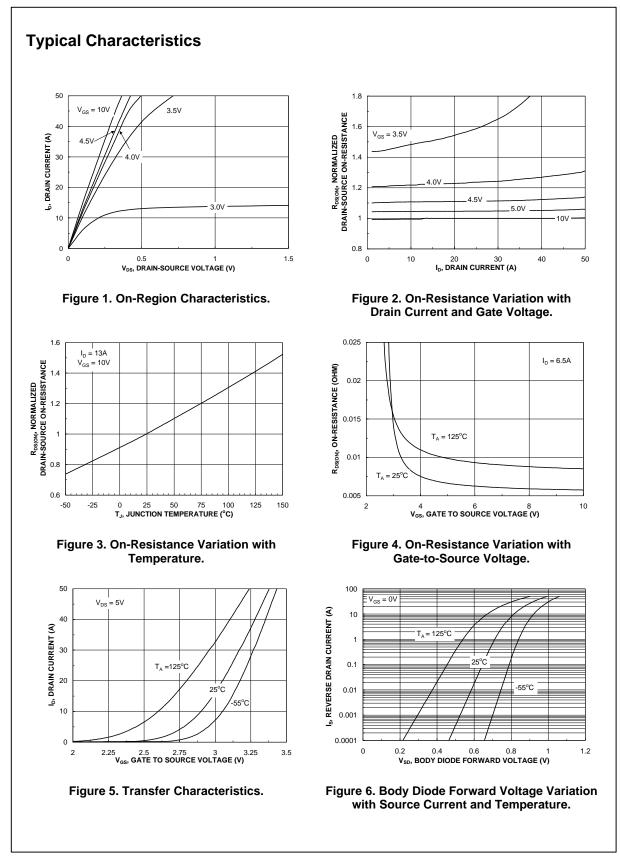
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics			l		
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	30			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C		26		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$, $V_{GS} = 0 V$			1	μA
		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 250 \ \mu A$	1	1.8	3	V
$\Delta V_{GS(th)}$ ΔT_J	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-5.3		mV/°C
R _{DS(on)}	Static Drain–Source	$V_{GS} = 10 \text{ V}, \qquad I_D = 13 \text{ A}$		6	8	mΩ
	On–Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 10.5 \text{ A}$		7.2	10	
		V_{GS} = 10 V, I_D = 13 A, T_J =125°C		8.5	14	<u> </u>
D(on)	On–State Drain Current	$V_{GS} = 10 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	50			A
g fs	Forward Transconductance	$V_{DS} = 15 \text{ V}, \qquad I_D = 13 \text{ A}$		55		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 15 V$, $V_{GS} = 0 V$,		2220		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		535		pF
C _{rss}	Reverse Transfer Capacitance			200		pF
R _G	Gate Resistance	V_{GS} = 15 mV, f = 1.0 MHz		1.7		Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 10 V$, $I_D = 1 A$,		11	19	ns
tr	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		13	24	ns
t _{d(off)}	Turn-Off Delay Time			40	64	ns
t _f	Turn–Off Fall Time			13	24	ns
Qg	Total Gate Charge	$V_{DS} = 15 \text{ V}, \qquad I_D = 13 \text{ A},$		21	30	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = 5 V$		6		nC
Q _{gd}	Gate–Drain Charge			7		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source				2.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = 2.1 A$ (Note 2)		0.7	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = 13 \text{ A}, \qquad d_{iF}/d_t = 100 \text{ A}/\mu \text{s}$		31		nS
Q _{rr}	Diode Reverse Recovery Charge	$T_{\rm F} = 13 {\rm A}, \qquad u_{\rm iF}/u_{\rm f} = 100 {\rm A}/\mu{\rm s}$		21		nC

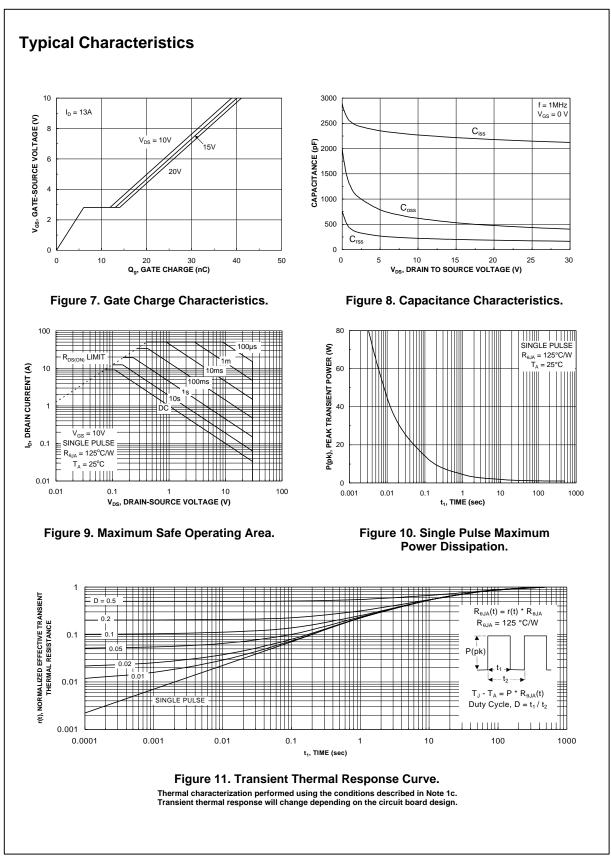
Scale 1 : 1 on letter size paper

2 Test: Pulse Width < 300µs, Duty Cycle < 2.0%

FDS6670A Rev F (W)



FDS6670A



FDS6670A

FDS6670A Rev F (W)

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